

## e.MMC Industrial

The Global Leader in Specialized Storage and Memory Solutions



## **KEY FEATURES**

- Robust Data Integrity\*
  (AutoRefresh and Dynamic Data Refresh)
- Extra-high endurance: 2-3X higher than standard e.MMC\*
- Smaller footprint package size\*

\* May vary by product and project support

- Complies with JEDEC e.MMC v5.1 Standard (JESD84-B51)
- 153-ball FBGA (RoHS compliant, "green package")
- LDPC ECC engine\*

The ATP industrial e.MMC is an advanced storage solution that integrates NAND flash memory, a sophisticated flash controller, and a fast MultiMedia Card (MMC) interface in the same package. By incorporating these components in an integrated package, ATP e.MMC manages all background operations internally, freeing the host from handling low-level flash operations for faster and more efficient processing.

Smaller than a typical postage stamp, ATP e.MMC comes in a 153-ball fine pitch ball grid array (FBGA package). The tiny footprint makes it perfectly suitable for embedded systems with space constraints but require rugged endurance, reliability and durability in harsh environments.

ATP e.MMC is built to meet the tough demands of industrial applications. As a soldered-down solution, it is secure against constant vibrations. Its industrial temperature rating means that severe scenarios from freezing cold -40°C to blistering hot 105°C will not cause adverse impact on the device or the data in it.

Compliant with the latest JEDEC e.MMC 5.1 Standard (JESD84-B51), ATP e.MMC features Command Queuing and Cache Barrier to enhance random read/write performance; High Speed 400 (HS400) DDR Mode for a bandwidth of up to 400 MB/s; and field firmware update (FFU). Enhanced Strobe in HS400 Mode facilitates faster synchronization between the host and the e.MMC device; and, Secure Write Protection ensures that only trusted entities can protect or unprotect the e.MMC device.

It is backward compatible with previous versions (v4.41/v4.5/v5.0), supporting features such as power-off notifications, packed commands, cache, boot or replay protected memory block (RPMB) partitions, high priority interrupt (HPI), and hardware (HW) reset.

										ETEDP
	0	0	0	0	0	0	0	0	<b>A</b>	0
	0	0	0	0	0	0	0	0		0
	0	0	0	0	0	0	0	0	0	

▲: Customization option available on a project basis.

## Specifications

		Extended Inc	lustrial Grade		Industrial Grade						
	Prer					Premium	Superior				
	E700Pa	E700Pa	E600Sa	E600Sa	E700Pi	E700Pi	E700Pi	E600Si	E600Si		
	3D MLC (pSLC mode)	) 2D MLC (pSLC mode)	3D MLC	2D MLC		3D MLC (pSLC mode)	2D MLC (pSLC mode)	3D TLC	3D MLC		
IC Package	153-ball FBGA										
JEDEC Specification	v5.1, HS400										
Power Loss Protection Options	Firmware Based										
Operating Temperature		-40°C to 105°C					-40°C to 85°C				
Capacity <sup>1</sup>	8 GB to 64 GB	4 GB to 8 GB	16 GB to 128 GB	8 GB to 16 GB	10 GB to 40 GB	8 GB to 64 GB	4 GB to 8 GB	32 GB to 128 GB	16 GB to 128 GB		
	Performance										
Sequential Read/ Write up to (MB/s) (Max.) <sup>2</sup>	300 / 240	230 / 100	300 / 170	230 / 100	290 / 225	300 / 240	230 / 100	290 / 225	300 / 170		
Bus Speed Modes	x1 / x4 / x8										
ICC (Typical RMS in Read/Write) mA (Max.)	145 / 175	85 / 65	125 / 175	85 / 50	100 / 110	145 / 175	85 / 65	100 / 110	125 / 175		
ICCQ (Typical RMS in Read/Write) mA (Max.)	120 / 100	60 / 45	115 / 95	60 / 30	105 / 100	120 / 100	60 / 45	105 / 100	110 / 100		
				Endurance a	nd Reliability						
Endurance TBW <sup>2</sup> (Max.)	1,213 TB	200 TB	824 TB	40 TB	1,364 TB	1,213 TB	200 TB	52 TB	824 TB		
Reliability MTBF @ 25°C	>2,000,000 hours	>3,000,000 hours	>2,000,000 hours	>3,000,000 hours	>2,000,0	000 hours	>3,000,000 hours	>2,000,00	00 hours		
				Oth	ners						
Dimensions (mm)	11.5 x 13.0 x 1.3	11.5 x 13.0 x 1.0	11.5 x 13.0 x 1.3	11.5 x 13.0 x 1.0	11.5 x 13.0 x 1.0	11.5 x 13.0 x 1.3	11.5 x 13.0 x 1.0	11.5 x 13.0 x 1.0	11.5 x 13.0 x 1.3		
Certifications				RoHS,	REACH						
Warranty				One	Year						
	Industrial Grade				Commercial Grade						
	Superior E600Si	Value E600Vi	Prei E700Pc	mium E700Pc	Sup E600Sc	erior E600Sc	Value E600Vc				
Flash Type	2D MLC	3D TLC		2D MLC (pSLC mode)		2D MLC	3D TLC				
IC Package				all FBGA							
JEDEC Specification				HS400							
Power Loss Protection Options			Firmwa	re Based							
Operating Temperature	-40°C	to 85°C									
Capacity <sup>1</sup>					-25°C to 85°C						
	8 GB to 16 GB	32 GB to 64 GB	10 GB to 40 GB	4 GB to 8 GB	-25°C to 85°C 32 GB to 128 GB	8 GB to 16 GB	32 GB to 64 GB				
	8 GB to 16 GB	32 GB to 64 GB		4 GB to 8 GB		8 GB to 16 GB	32 GB to 64 GB				
Sequential Read/ Write up to (MB/s) (Max.) <sup>2</sup>	8 GB to 16 GB 230 / 100	32 GB to 64 GB 290 / 225				8 GB to 16 GB 230 / 100	32 GB to 64 GB 290 / 225				
			Perfo	rmance 230 / 100	32 GB to 128 GB						
Write up to (MB/s) (Max.) <sup>2</sup>			Perfo 290 / 225	rmance 230 / 100	32 GB to 128 GB						
Write up to (MB/s) (Max.) <sup>2</sup> Bus Speed Modes ICC (Typical RMS	230 / 100	290 / 225	Perfo 290 / 225 x1 / x4	rmance 230 / 100 4 / x8	32 GB to 128 GB 290 / 225	230 / 100	290 / 225				
Write up to (MB/s) (Max.) <sup>2</sup> Bus Speed Modes ICC (Typical RMS in Read/Write) mA (Max.) ICCQ (Typical RMS	230 / 100 85 / 50	290 / 225 100 / 110	Perfor 290 / 225 x1 / x4 100 / 110 105 / 100	rmance 230 / 100 4 / x8 85 / 65	32 GB to 128 GB 290 / 225 100 / 110	230 / 100 85 / 50	290 / 225 100 / 110				
Write up to (MB/s) (Max.) <sup>2</sup> Bus Speed Modes ICC (Typical RMS in Read/Write) mA (Max.) ICCQ (Typical RMS	230 / 100 85 / 50	290 / 225 100 / 110	Perfor 290 / 225 x1 / x4 100 / 110 105 / 100	rmance 230 / 100 4 / x8 85 / 65 60 / 45	32 GB to 128 GB 290 / 225 100 / 110	230 / 100 85 / 50	290 / 225 100 / 110				
Write up to (MB/s) (Max.) <sup>2</sup> Bus Speed Modes ICC (Typical RMS in Read/Write) mA (Max.) ICCQ (Typical RMS in Read/Write) mA (Max.) Endurance TBW <sup>2</sup>	230 / 100 85 / 50 60 / 30 40 TB	290 / 225 100 / 110 105 / 100 20 TB	Perfor 290 / 225 x1 / x 100 / 110 105 / 100 Endurance a 1,364 TB	rmance 230 / 100 4 / x8 85 / 65 60 / 45 and Reliability 200 TB	32 GB to 128 GB 290 / 225 100 / 110 105 / 100 52 TB	230 / 100 85 / 50 60 / 30 40 TB	290 / 225 100 / 110 105 / 100 20 TB				
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Write up to (MB/s) (Max.) <sup>2</sup> Bus Speed Modes ICC (Typical RMS in Read/Write) mA (Max.) ICCQ (Typical RMS in Read/Write) mA (Max.) Endurance TBW <sup>2</sup> (Max.) Reliability MTBF @ 25°C	230 / 100 85 / 50 60 / 30 40 TB >3,000,000 hours	290 / 225 100 / 110 105 / 100 20 TB >2,000,000 hours	Perfor 290 / 225 x1 / xx 100 / 110 105 / 100 Endurance a 1,364 TB >2,000,000 hours 0tt	rmance 230 / 100 4 / x8 85 / 65 60 / 45 and Reliability 200 TB >3,000,000 hours hers	32 GB to 128 GB 290 / 225 100 / 110 105 / 100 52 TB >2,000,000 hours	230 / 100 85 / 50 60 / 30 40 TB >3,000,000 hours	290 / 225 100 / 110 105 / 100 20 TB >2,000,000 hours				

1 Low-density parity-check error correcting code. By product support. 2 All performance is collected or measured using ATP proprietary test environment, without file system overhead.



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Product spec and its related information are subject to change without advance notice.

Please refer to <u>www.atpinc.com</u> for latest information

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ATP TAIWAN (HQ)

TEL: +886-2-2659-6368 sales-apac@atpinc.com

ATP USA

ATP EUROPE

ATP JAPAN

ATP CHINA

TEL: +86-21-5080-2220

ATP INDIA

TEL: +1-408-732-5000 sales@atpinc.com

TEL: +49-89-374-9999-0 sales-europe@atpinc.com

TEL: +81-3-6260-0797 sales-japan@atpinc.com sales@cn.atpinc.com

sales-india@atpinc.com